Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Function For Which Designed:
Rectifier and switching
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 reverse voltage, dc and 40.0 forward voltage, dc
Current Rating Per Characteristic:
175.00 milliamperes forward current, average peak
Power Rating Per Characteristic:
320.0 milliwatts small-signal input power, common-collector preset
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
4 uninsulated wire lead
Specification Data:
19200-11728115 manufacturers source control
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0